

Supporting Information

Trivalent Ions Mediated Abnormal Growth of All-Inorganic Perovskite Nanocrystals and the Divergent Emission Properties

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1. Characterization of perovskite CsPbBr₃ NC achieved by one-pot synthesis

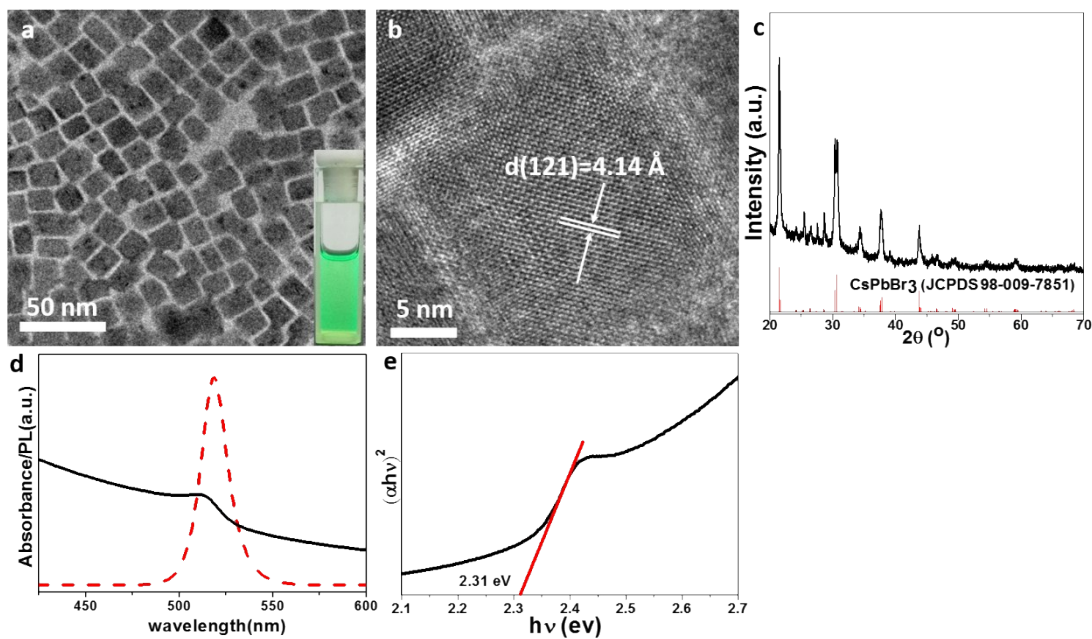


Fig. S1. TEM (a) and HRTEM (b) images, XRD pattern (c), optical absorbance (black line) and PL emission (red line) spectra (d), and Tauc plot (e) of the CsPbBr₃ NCs achieved by one-pot synthesis under Ar atmosphere, in the absence of any foreign cations. Inset in panel a) presents the photograph of CsPbBr₃ NCs dispersed in hexane under UV light illumination (355 nm excitation wavelength).

2. Characterization of the Bi-doped CsPbBr₃ NCs formed in the presence of BiBr₃

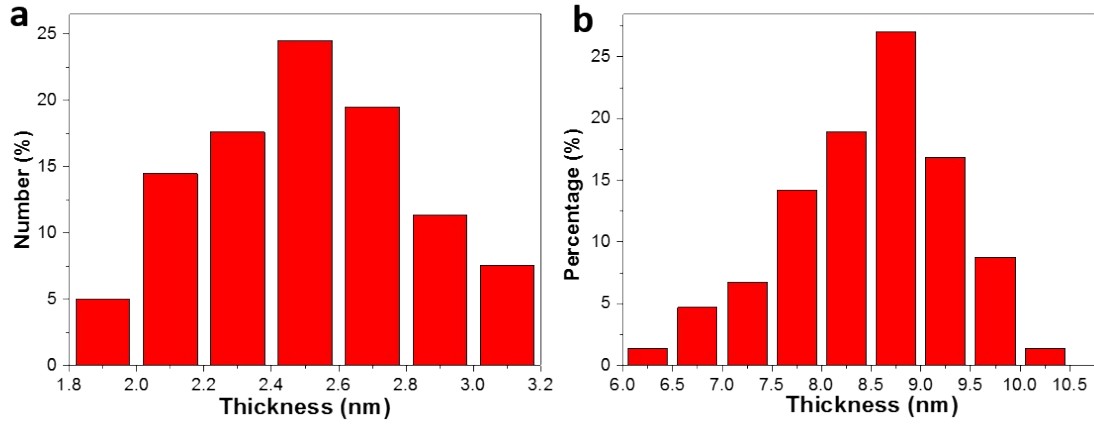


Fig. S2. Size (in thickness) distribution histogram for the two NPL populations of CsPbBr₃ with different average thicknesses. The corresponding TEM images for the size calculation are from panels b) and c) of the Fig. 1 in the main text. The average thicknesses of the two NPLs populations are calculated to be 2.5 ± 0.3 nm, 8.5 ± 0.8 nm, respectively.

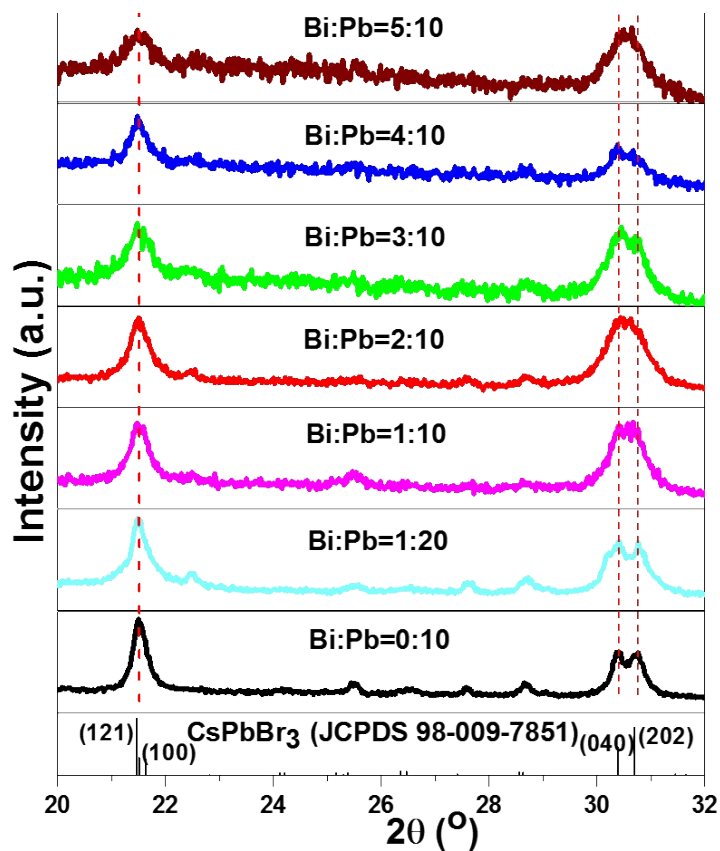


Fig. S3. XRD patterns of the CsPbBr₃ NCs achieved with different precursor Bi:Pb ratios as dictated.

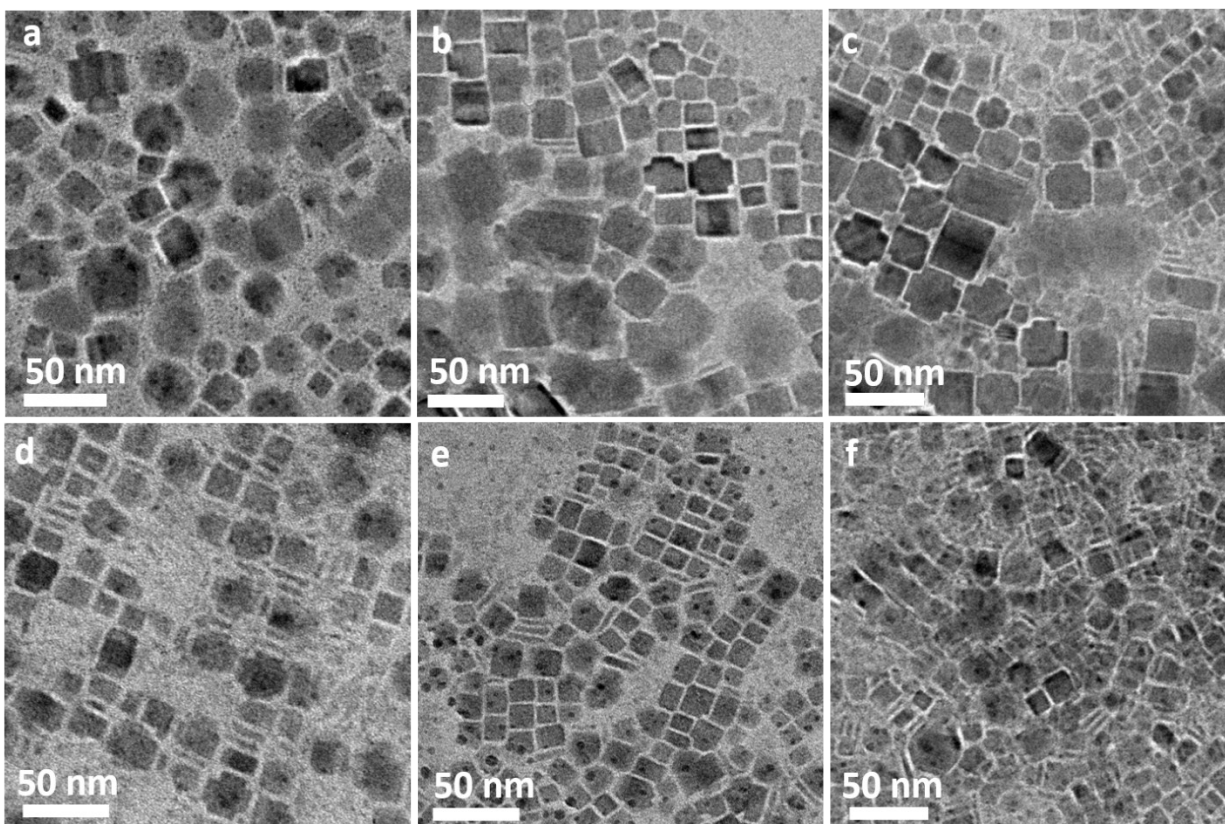


Fig. S4. TEM images of the crude CsPbBr_3 perovskite NCs as-achieved with precursor Bi:Pb ratios of 1:20 (a), 1:10 (b), 2:10 (c), 3:10 (d), 4:10 (e) and 5:10 (f).

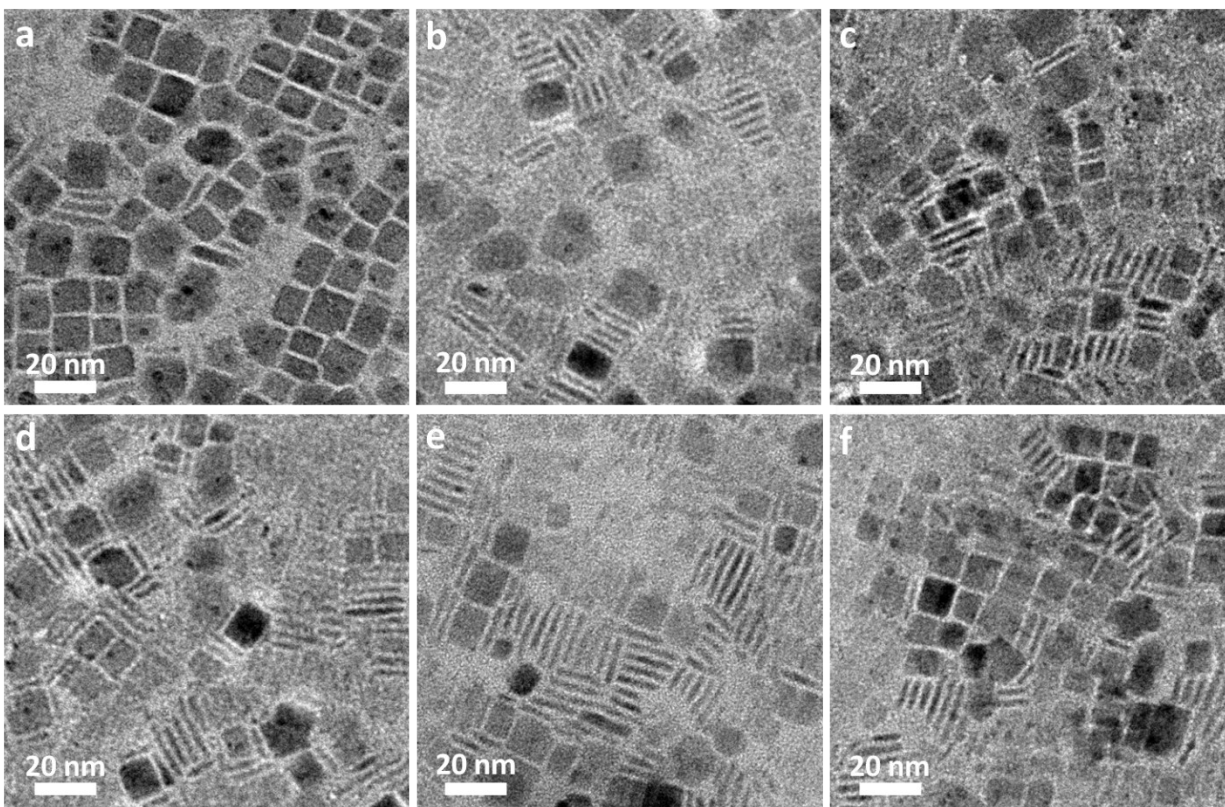


Fig. S5. TEM images of the perovskite CsPbBr_3 NPLs with small thickness of ~ 2.5 nm. The NPLs were collected by centrifugation selection of the various samples as-formed with precursor Bi:Pb ratios of 1:20 (a), 1:10 (b), 2:10 (c), 3:10 (d), 4:10 (e) and 5:10 (f).

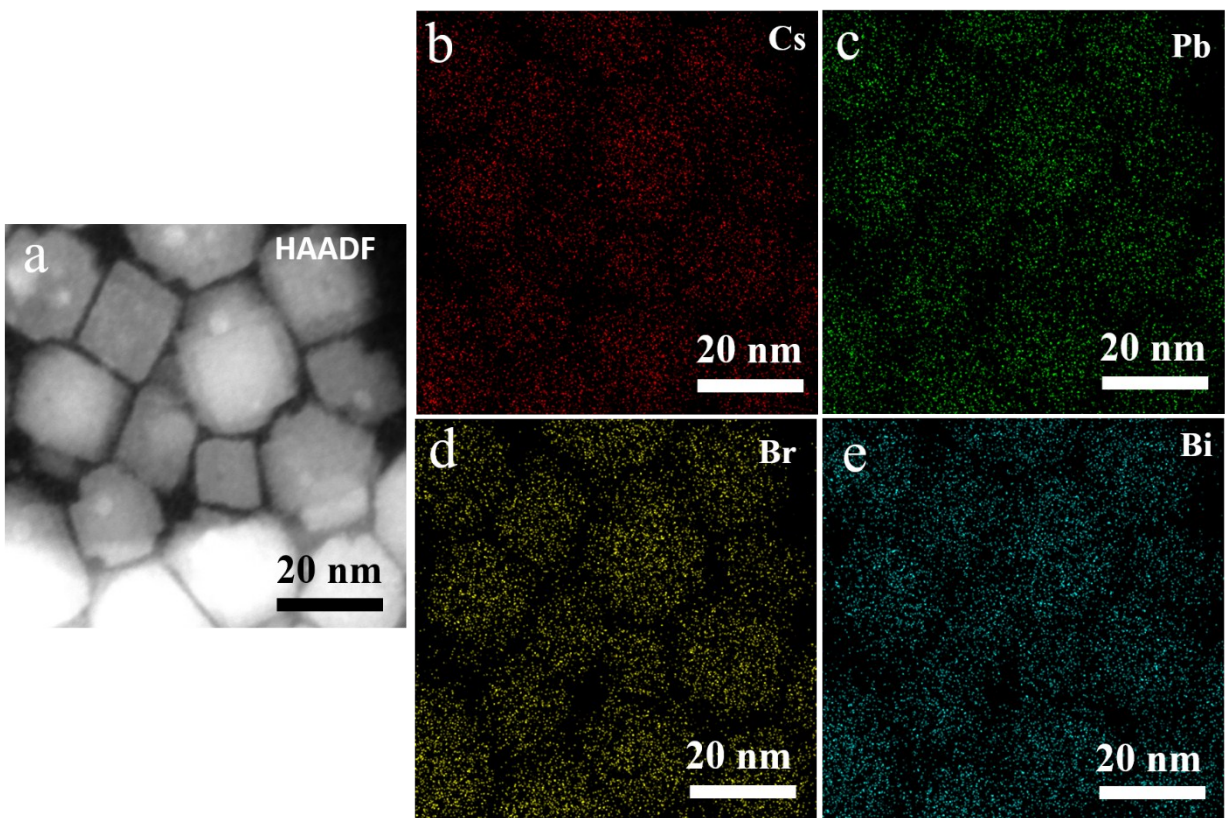


Fig. S6. (a) HAADF-STEM image of the Bi-doped CsPbBr_3 NPLs with small thickness of ~ 2.5 nm, and the corresponding maps of (b) Cs, (c) Pb, (d) Br, and (e) Bi, demonstrating the presence of different elements in the Bi-doped perovskite NCs. The NPLs were collected by centrifugation selection.

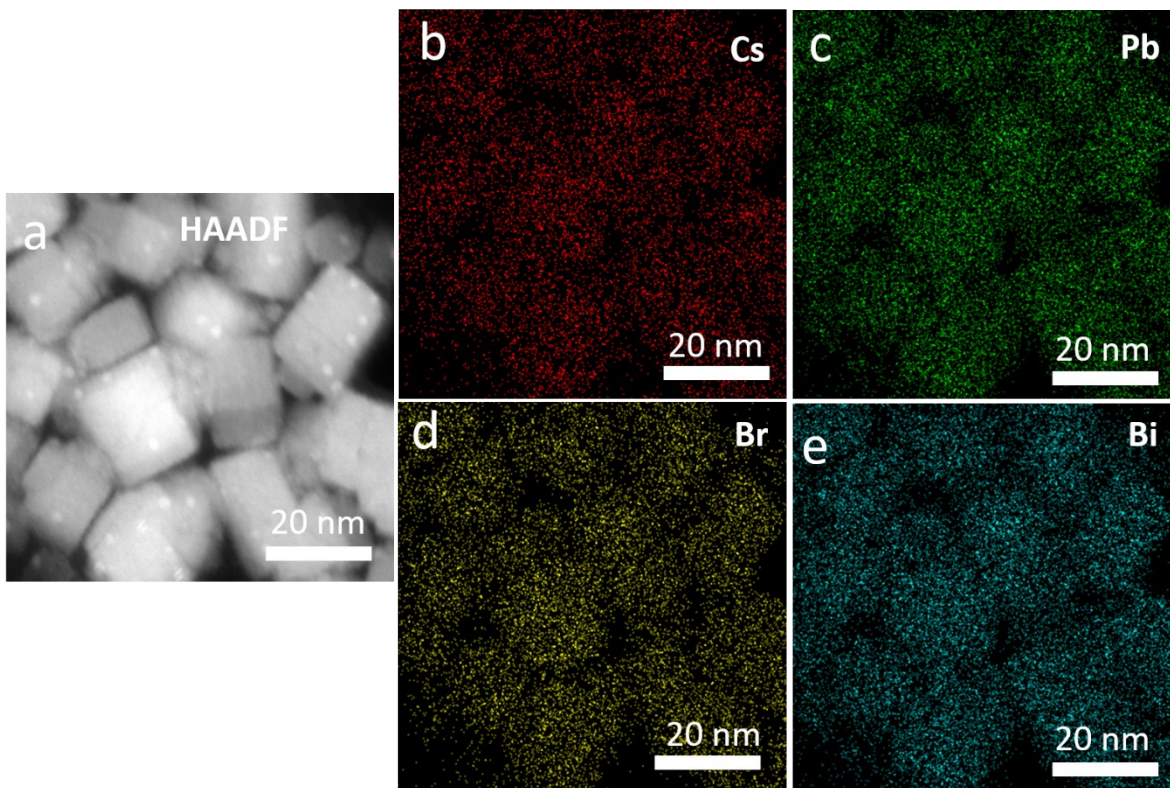


Fig. S7. (a) HAADF-STEM image of the thick Bi-doped CsPbBr_3 NPLs collected by size selection and the corresponding maps of (b) Cs, (c) Pb, (d) Br, and (e) Bi, demonstrating the presence of different elements in the Bi-doped perovskite NCs.

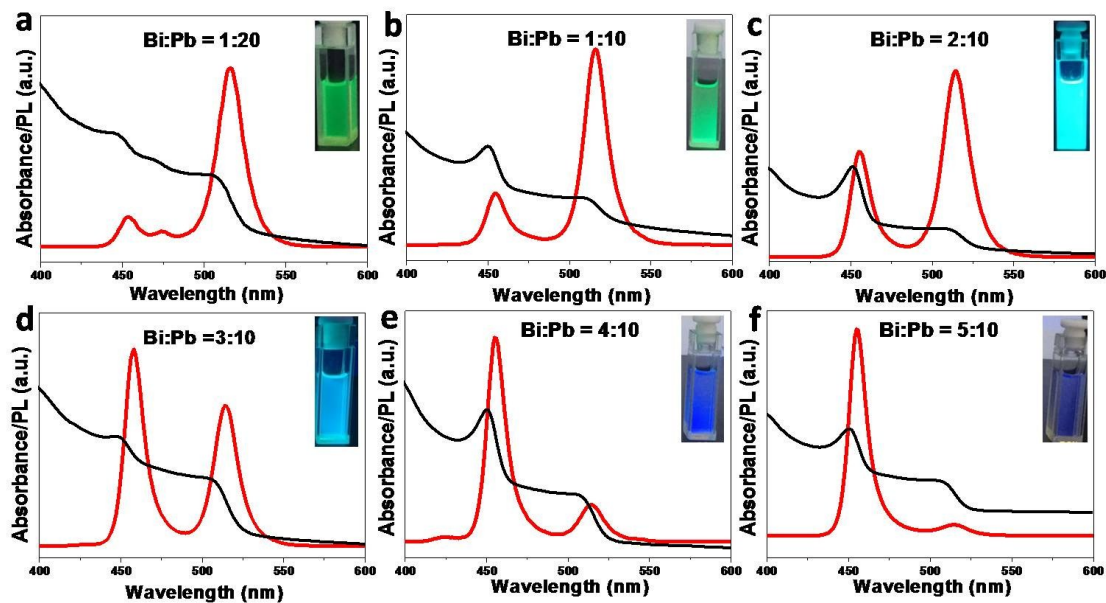


Fig. S8. Optical absorbance (black lines) and PL spectra (red lines) of the various CsPbBr_3 NCs achieved with different precursor Bi:Pb ratios as dictated.

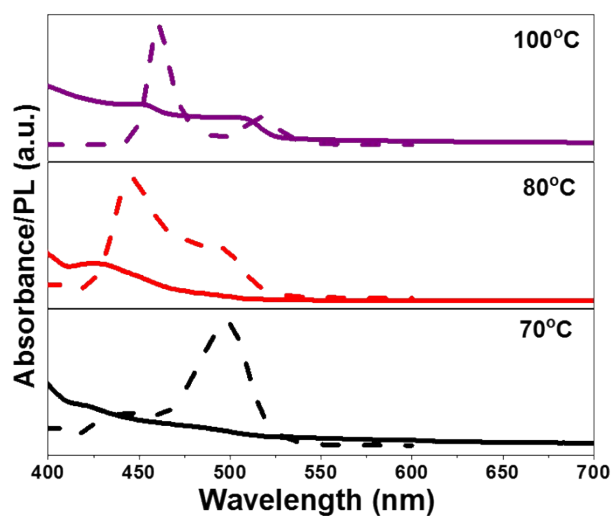


Fig. S9. The steady-state absorption spectra (solid curves) and PL spectra (dash curves) of the aliquots collected at different temperatures during heating up. The samples are collected in the presence of BiBr_3 by fixing Bi:Pb as 4:10.

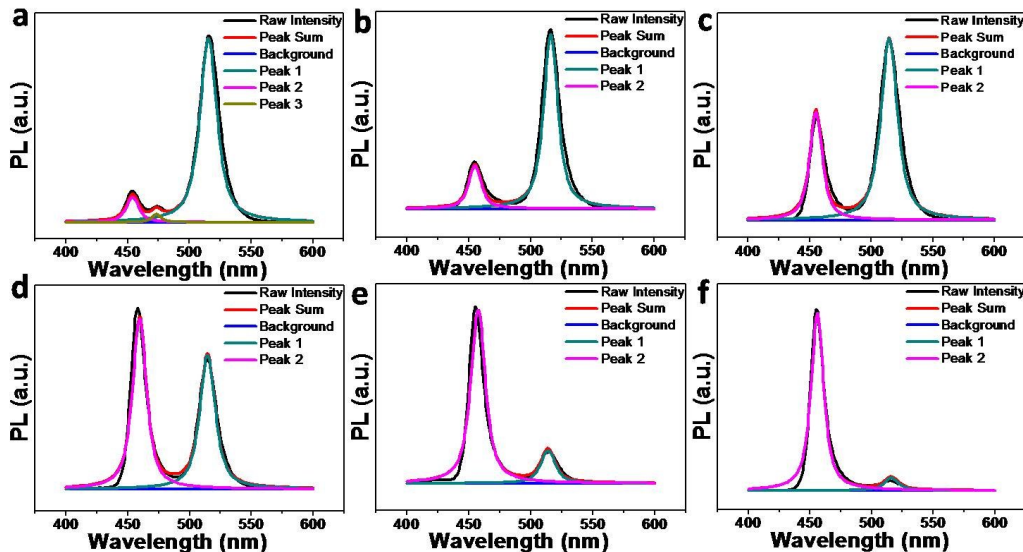


Fig. S10. Multi-peak fitting of the PL spectra for the CsPbBr_3 NCs achieved with precursor Bi:Pb ratios of 1:20 (a), 1:10 (b), 2:10 (c), 3:10 (d), 4:10 (e) and 5:10 (f). The multi-peak-emitting spectra were fitted by the type of Gaussian. The peak positions extracted from the fit are listed in Table S1. The results indicate that the as-synthesized samples consist of NPLs with different sized (in thickness).

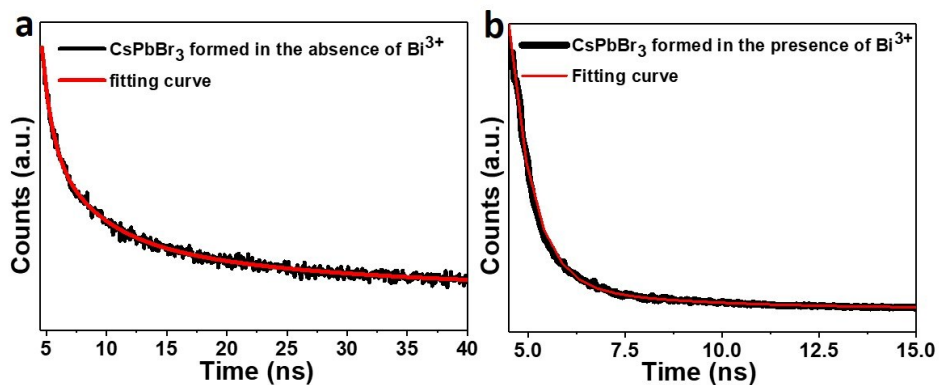


Fig. S11. Time-resolved PL decay spectra (excitation at 510 nm) and the corresponding fitted curves of the CsPbBr_3 NCs in the absence (a) and presence (b) of Bi^{3+} , respectively. PL decay curves were well fitted with tri-exponential function.

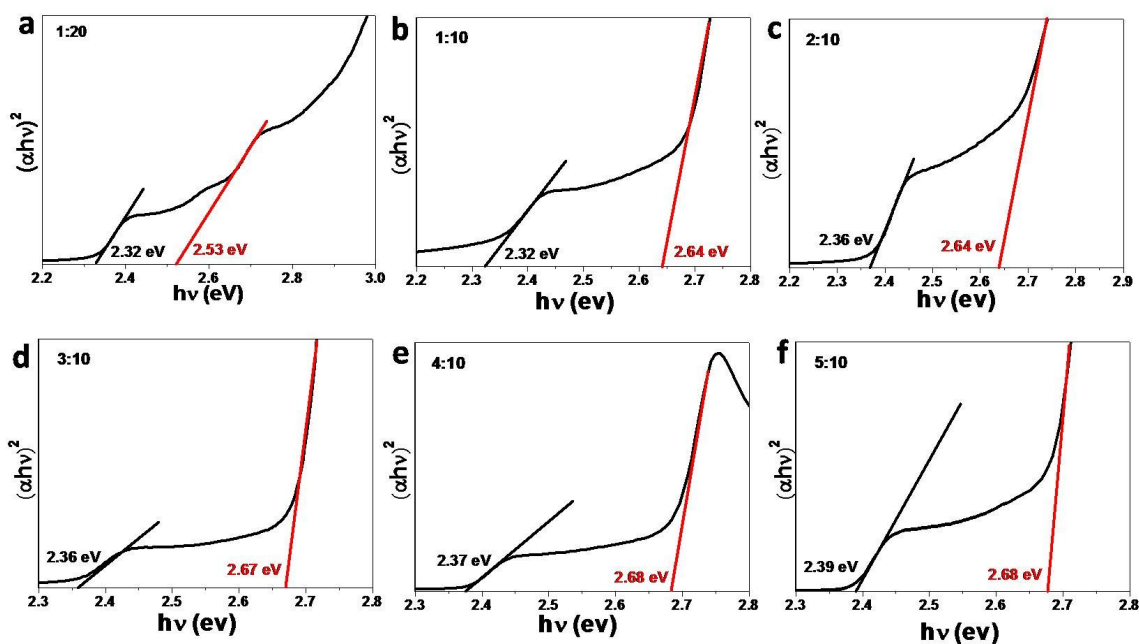


Fig. S12. Tauc plots of undoped CsPbBr_3 NCs (a) and CsPbBr_3 NCs formed in the presence of different amount of Bi^{3+} ions in the precursor (labelled as feed Bi:Pb ratio) as dictated.

Table S1. The summarization on the optical characterization of the CsPbBr_3 NCs achieved in the presence of different amount of Bi^{3+} ions in the precursor (labelled as feed Bi:Pb ratio). The band gaps (E_g) are estimated from Tauc formula.

| Feed Bi:Pb ratio | Dual PL peaks ^a (nm) | | E_g (eV) | | FWHM ^b (nm) | | Final Bi:Pb ratio (found by ICP) |
|------------------|---------------------------------|-------|------------|-------|------------------------|-------|----------------------------------|
| | Peak1 | Peak2 | Peak1 | Peak2 | Peak1 | Peak2 | |
| 0:10 | 518.6 | | 2.31 | | 17.31 | | 0% |
| 1:20 | 515.4 | 454.0 | 2.32 | 2.53 | 16.50 | 12.00 | 0.8% |
| 1:10 | 516.2 | 455.0 | 2.32 | 2.64 | 13.60 | 12.00 | 3.0% |

| | | | | | | | |
|------|-------|-------|------|------|-------|-------|-------|
| 2:10 | 514.4 | 455.0 | 2.36 | 2.64 | 16.00 | 12.20 | 4.9% |
| 3:10 | 514.3 | 458.4 | 2.36 | 2.67 | 15.00 | 13.00 | 7.2% |
| 4:10 | 513.9 | 457.5 | 2.37 | 2.68 | 14.00 | 14.00 | 10.8% |
| 5:10 | 515.0 | 456.1 | 2.39 | 2.68 | 15.00 | 12.30 | 13.7% |

^a Dual PL peaks after deconvolution.

^b Full width at half-maximum (FWHM) of each PL peak after deconvolution.

Table S2. Photoluminescence quantum yields (PLQY) of the typical perovskite NCs. The Bi:Pb ratio in the precursor is 2:10.

| Samples | Bi:Pb (% , found by ICP) | PLQY (%) |
|---|--------------------------|----------|
| CsPbBr ₃ formed in the absence of Bi | 0 | 19.67 |
| CsPbBr ₃ formed in the presence of BiBr ₃ | 4.9 | 43.96 |
| CsPbCl _x Br _{3-x} formed in the presence of BiCl ₃ | 4.9 | 9.52 |

Table S3. Final Bi:Pb ratio of the typical thin NPLs groups and thick particles upon centrifugation at low centrifugal velocity.

| Feed Bi:Pb ratio | Groups of particles | Final Bi:Pb ratio (found by ICP) | Final Bi:Pb ratio (found by EDS) |
|------------------|---------------------|----------------------------------|----------------------------------|
| 3:10 | Thin NPLs | 8.3:100 | 6.9:100 |
| | Thick particles | 7.0:100 | 6.3:100 |

3. Characterization of the CsPbBr₃ NCs achieved in the presence of BiFeO₃

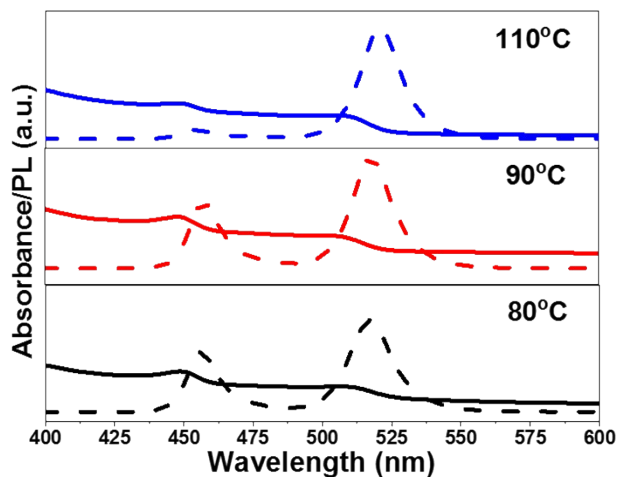


Fig. S13. Optical absorbance spectra (solid curves) and PL spectra (dash curves) of the various CsPbBr₃ aliquots collected at different temperatures as dictated. The CsPbBr₃ NCs achieved in the presence of BiFeO₃.

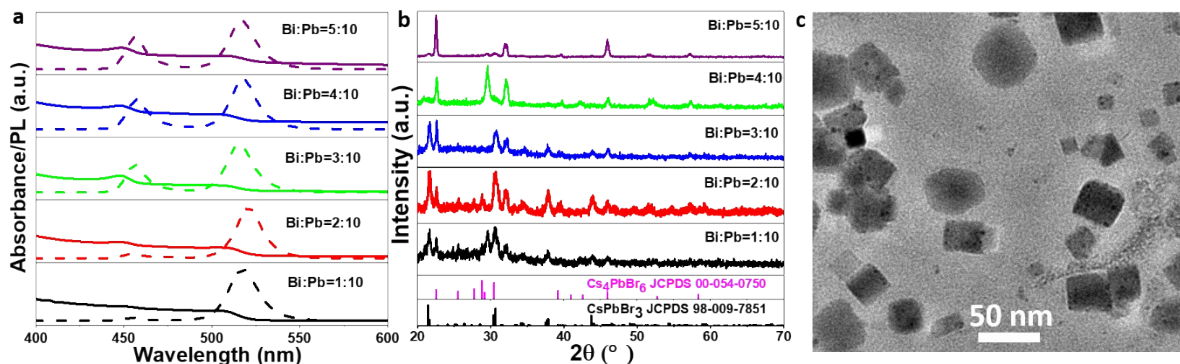


Fig. S14. (a) Optical absorbance spectra (solid curves) and PL spectra (dash curves), (b) XRD patterns of the various CsPbBr₃ NCs collected with different precursor Bi:Pb ratios as dictated. (c) TEM image of the typical NCs collected by fixing precursor Bi:Pb = 3:10. The NCs were achieved in the presence of BiFeO₃. XRD patterns indicate mixed phases in the resulting samples. TEM image suggests that the NCs are not uniform in morphology.

4. Characterization of the CsPbBr₃ NCs achieved in the presence of Al³⁺ ions

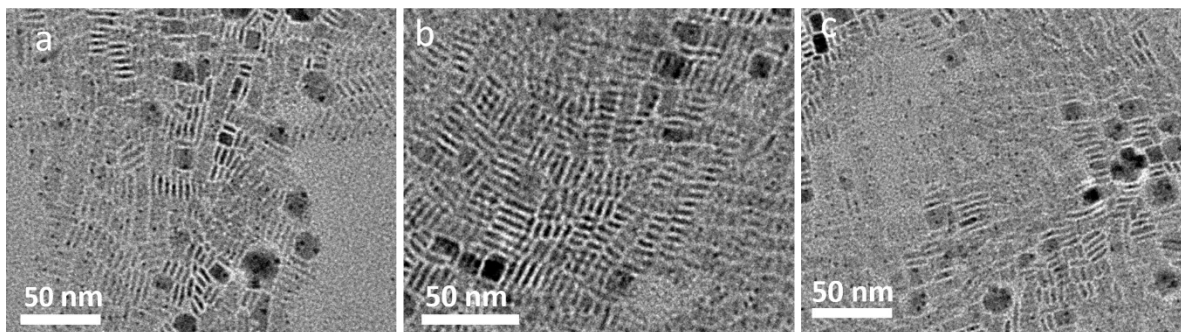


Fig. S15. TEM images of the CsPbBr₃ NPLs collected in the presence of AlBr₃ in the precursor by fixing Al:Pb ratios of 1:10 (a), 2:10 (b) and 3:10 (c), respectively.

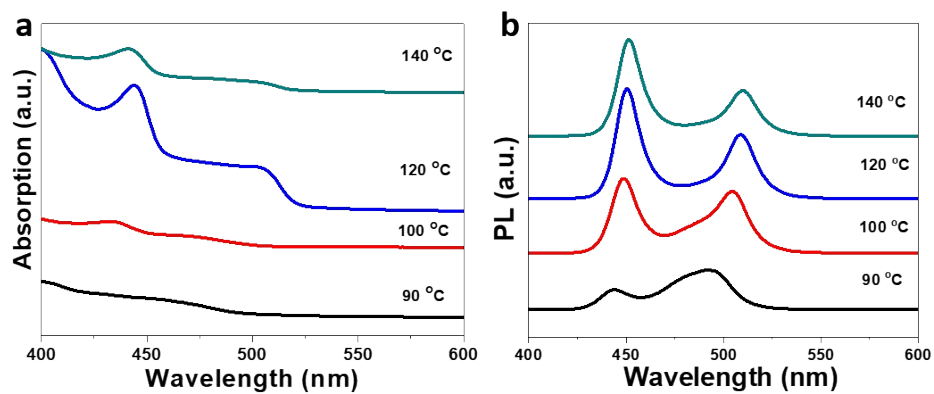


Fig. S16. Optical absorbance spectra (a) and PL spectra (b) and XRD patterns of the CsPbBr₃ NCs collected at different temperatures as dictated, in the presence of AlBr₃ by fixing Al:Pb ratios of 3:10.

5. Characterization of the CsPbBr₃ NCs achieved in the presence of In³⁺ ions

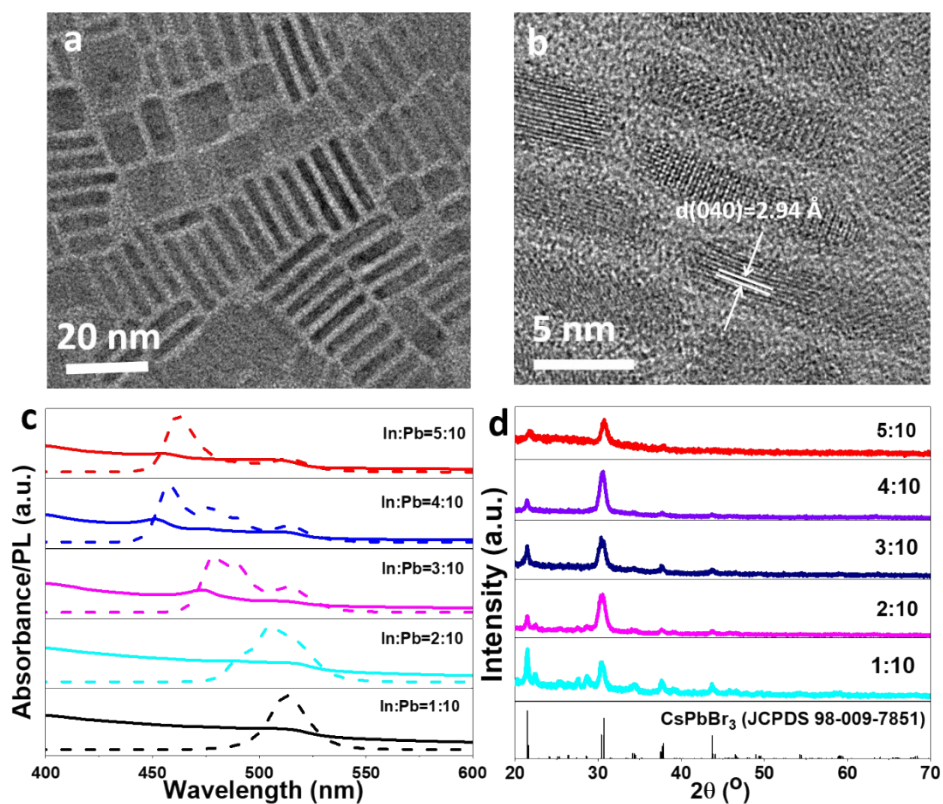


Fig. S17. (a-b) TEM (a) and HRTEM (b) images of the typical CsPbBr₃ NPLs synthesized in the presence of InBr₃. (c-d) Optical absorbance spectra and PL spectra (c) and XRD patterns (d) of various CsPbBr₃ NCs collected in the presence of different precursor In:Pb ratios as dictated.

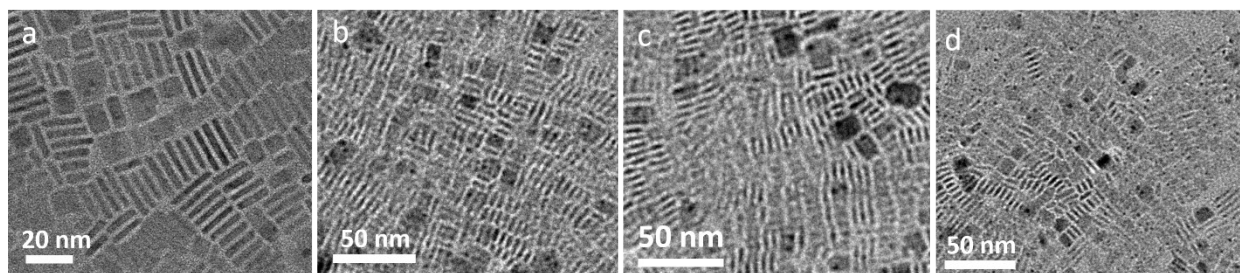


Fig. S18. TEM images of the CsPbBr₃ NPLs collected in the presence of InBr₃ by fixing In:Pb ratios of 1:10 (a), 2:10 (b) 3:10 (c) and 5:10 (d), respectively.

6. Characterizations of the $\text{CsPbCl}_x\text{Br}_{3-x}$ NCs achieved in the presence of BiCl_3

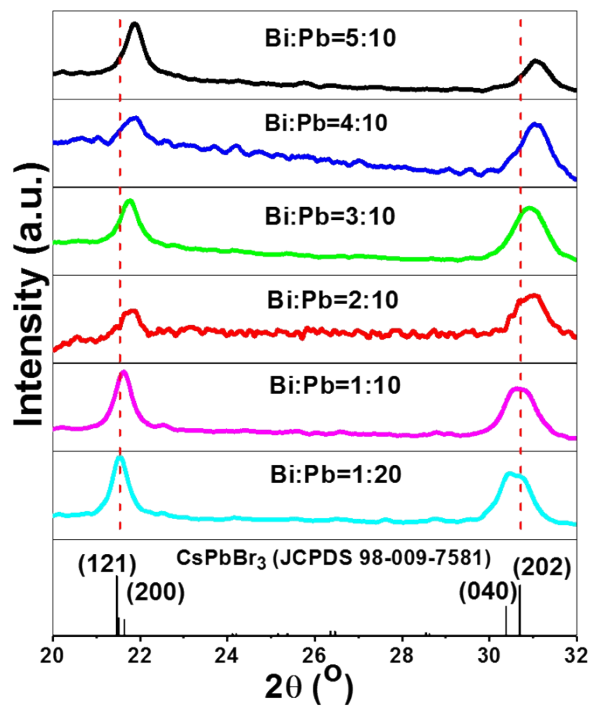


Fig. S19. XRD patterns of the $\text{CsPbCl}_x\text{Br}_{3-x}$ NCs achieved with different precursor Bi:Pb ratios as dictated. The samples were prepared in the presence of BiCl_3 .

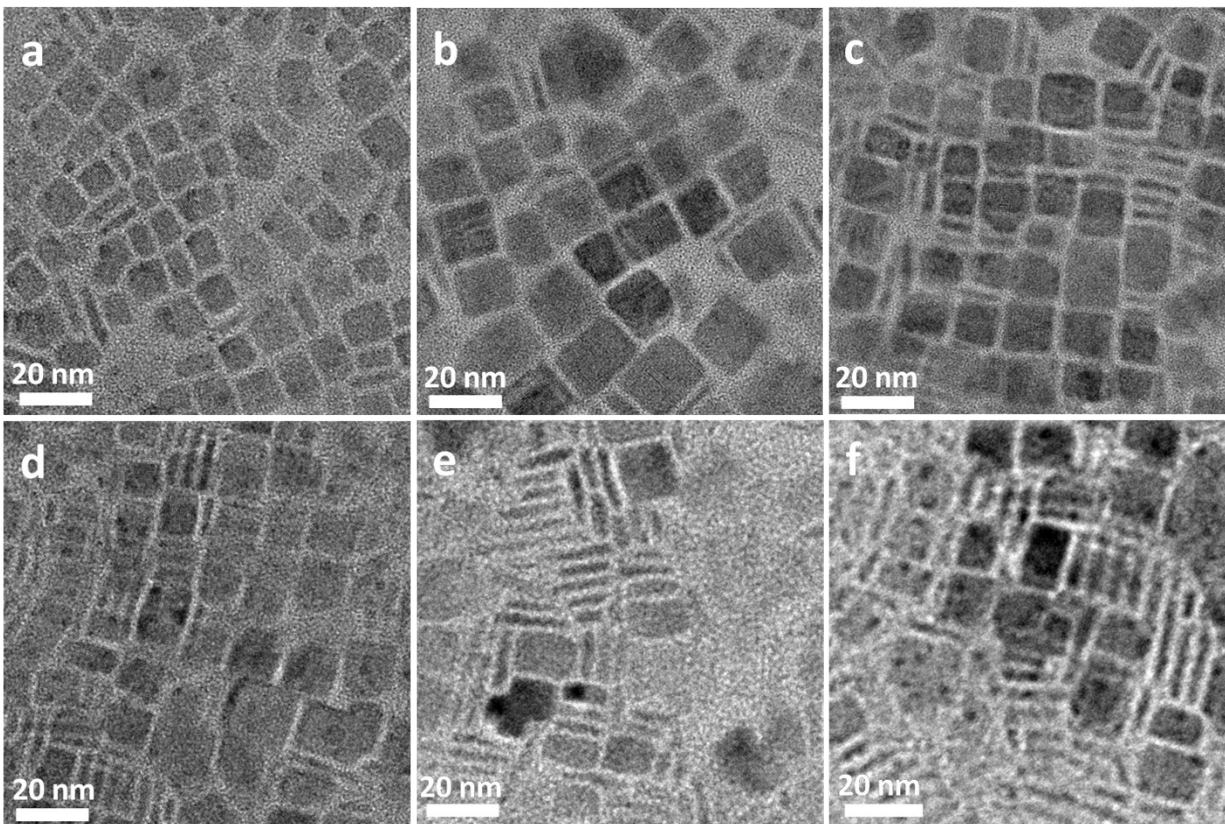


Fig. S20. TEM images of the perovskite $\text{CsPbCl}_x\text{Br}_{3-x}$ NPLs, which were collected from the top solution upon centrifugation selection of the various samples as-formed in the presence of precursor Bi:Pb ratios of 1:20 (a), 1:10 (b), 2:10 (c), 3:10 (d), 4:10 (e) and 5:10 (f). The samples were prepared in the presence of BiCl_3 .

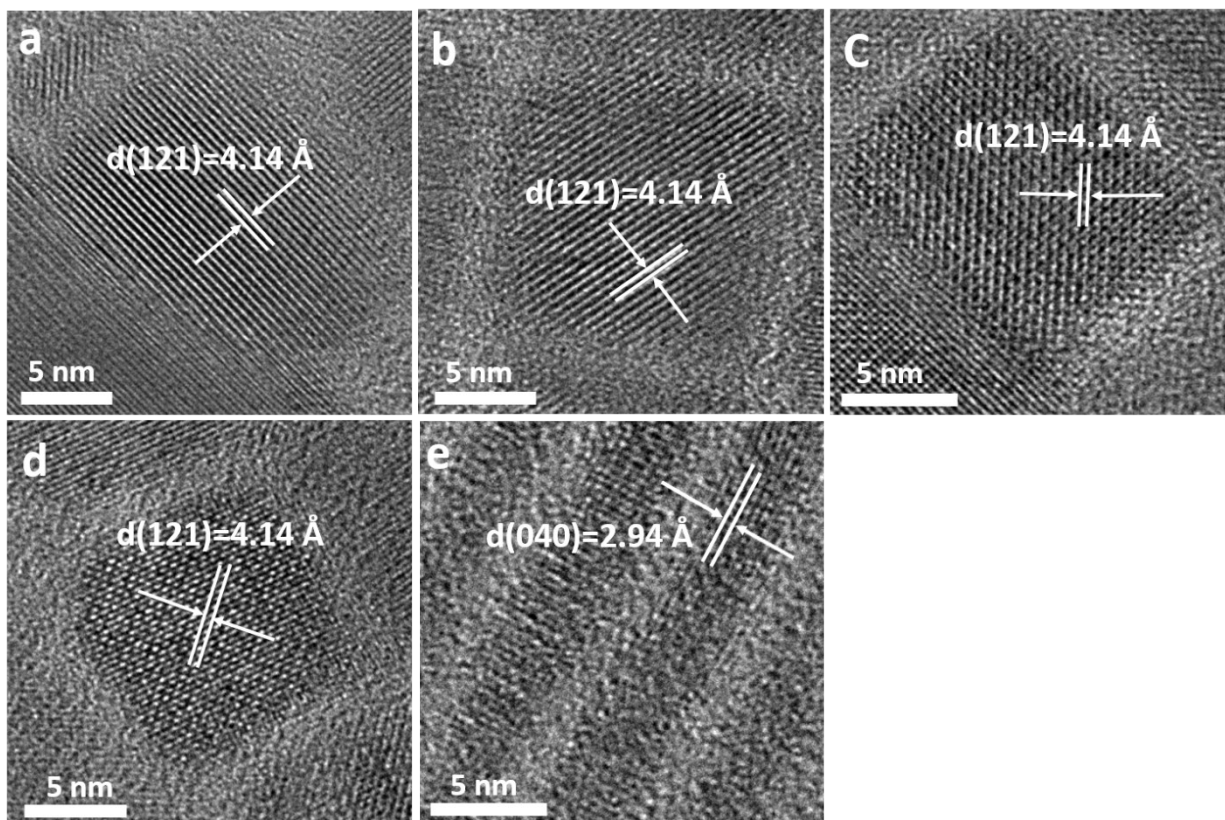


Fig. S21. (a-d) Top-view of HRTEM images of the representative individual perovskite CsPbBr₃ NPLs with average thickness of around 2.5 nm, which were achieved in the presence of precursor Bi:Pb ratios of 1:20 (a), 1:10 (a), 2:10 (b), 3:10 (c), and 4:10 (d). (e) side-view of HRTEM image of the individual perovskite CsPbBr₃ NPLs achieved with precursor Bi:Pb ratio of 2:10.

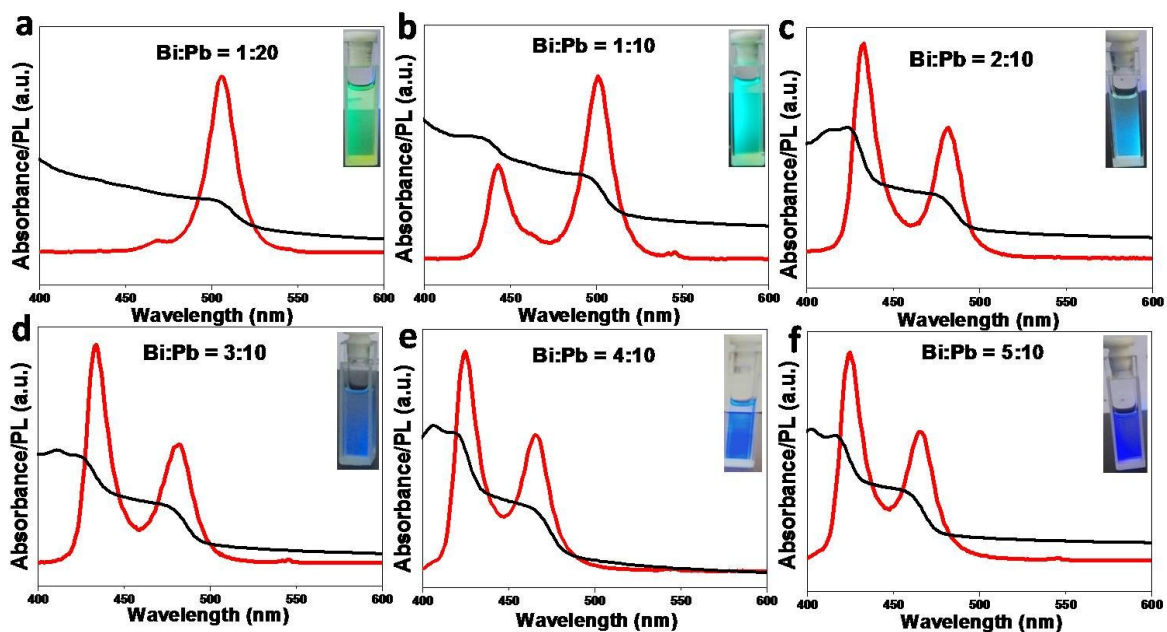


Fig. S22. Optical absorbance (black lines) and PL spectra (red lines) of the $\text{CsPbCl}_x\text{Br}_{3-x}$ NCs achieved with different precursor Bi:Pb ratios as dictated. Insets in each panel present the photographs of corresponding NCs dispersed in hexane under UV light illumination (355 nm excitation wavelength).

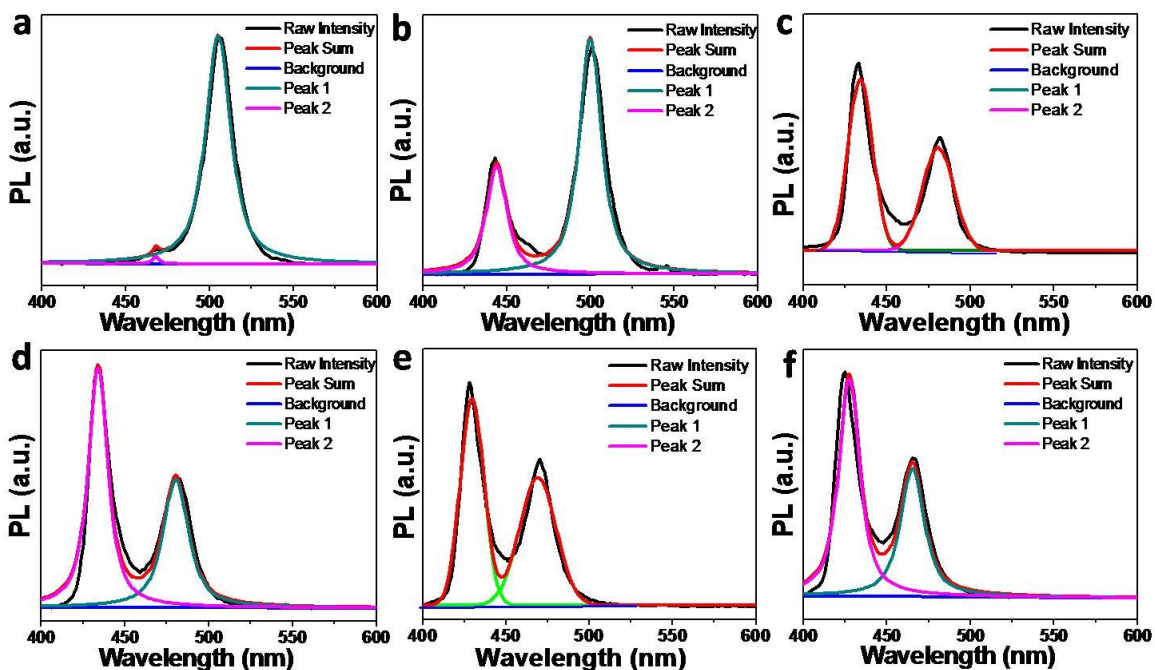


Fig. S23. Deconvolution of the PL spectra collected on the $\text{CsPbCl}_x\text{Br}_{3-x}$ NCs achieved with precursor Bi:Pb ratios of 1:20 (a), 1:10 (b), 2:10 (c), 3:10 (d), 4:10 (e) and 5:10 (f). For data fitting, a doublet was used for each PL spectrum.

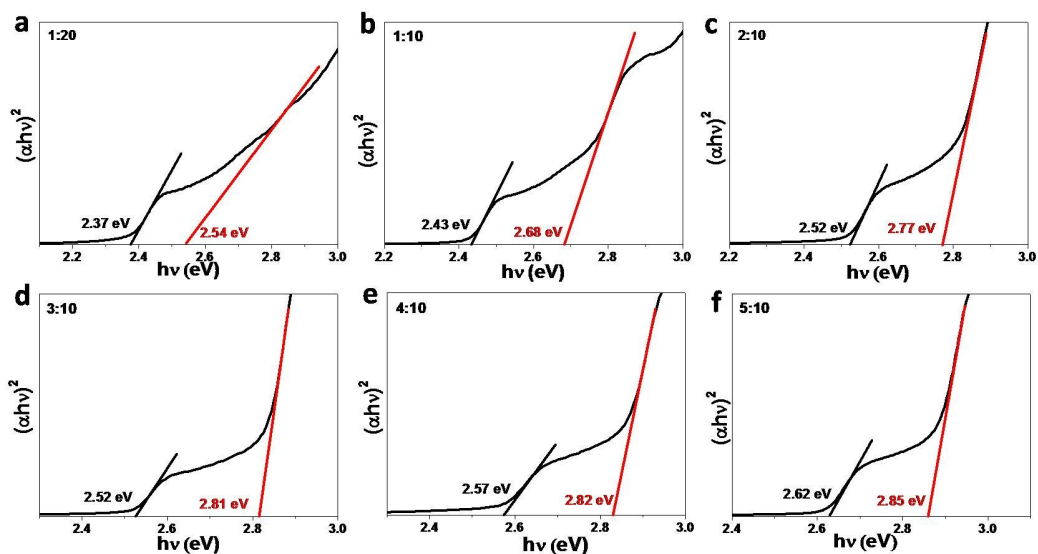


Fig. S24. Tauc plots of the $\text{CsPbCl}_x\text{Br}_{3-x}$ NCs formed in the presence of different precursor Bi:Pb ratios as dictated.

Table S4. The summarization on the optical characterization of the $\text{CsPbCl}_{3-x}\text{Br}_3$ NCs achieved in the presence of different Bi:Pb precursor ratios.

| Feed Bi:Pb ratio | Dual PL peaks ^a (nm) | | Band gap (eV) from Tauc formula | | FWHM ^b (nm) | | Final Bi:Pb ratio (found by ICP) |
|------------------|---------------------------------|-------|------------------------------------|-------|------------------------|-------|----------------------------------|
| | Peak1 | Peak2 | Peak1 | Peak2 | Peak1 | Peak2 | |
| 1:20 | 505.1 | 467.9 | 2.37 | 2.54 | 18.00 | 4.75 | 1.3% |
| 1:10 | 500.0 | 444.0 | 2.43 | 2.68 | 16.00 | 14.50 | 2.1% |
| 2:10 | 480.7 | 434.2 | 2.52 | 2.77 | 18.00 | 14.00 | 2.6% |
| 3:10 | 469.0 | 429.6 | 2.52 | 2.81 | 20.00 | 14.30 | 4.9% |
| 4:10 | 565.3 | 427.5 | 2.57 | 2.82 | 17.00 | 15.00 | 7.7% |
| 5:10 | 465.0 | 425.0 | 2.62 | 2.85 | 16.00 | 14.00 | 7.9% |

^a Dual PL peaks after deconvolution.

^b Full width at half-maximum of the dual PL peaks after deconvolution.

7. XPS analyses of the typical Bi-doped CsPbBr₃ NCs

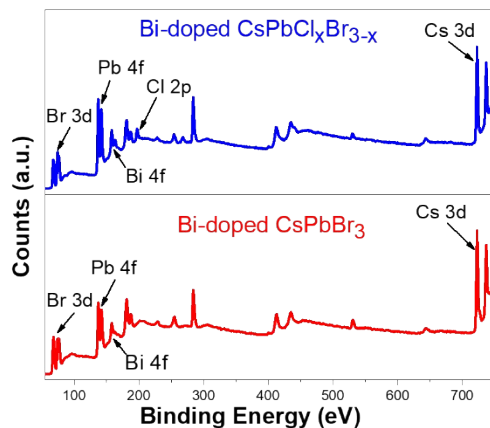


Fig. S25. Survey XPS spectra of the typical Bi-doped NCs as dictated. It is noteworthy that Bi signal can be detected in all the doped NCs. XPS analyses further confirm that the elemental composition of the doped CsPbBr₃ and CsPbCl_xBr_{3-x} NCs contains Cs, Pb, Bi and Br.

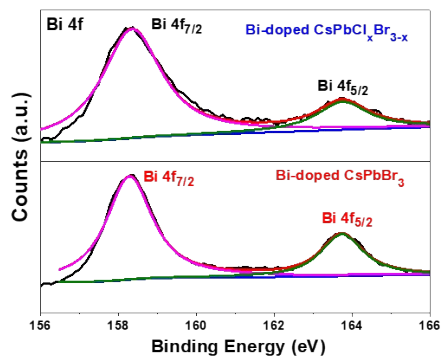


Fig. S26. Deconvolution of the Bi 4f high-resolution XPS signals collected on the Bi-doped perovskite CsPbBr₃ and CsPbCl_xBr_{3-x} NCs formed in the presence of BiBr₃ and BiCl₃, respectively.

8. Details of computation

The density functional theory calculations were performed with the Vienna Ab-initio Simulation Package (VASP). The functional of choice was PBE. The inner electrons were represented by projector-augmented wave pseudopotentials (PAW), and the mono-electronic states were expanded in plane waves with a kinetic energy cutoff of 400 eV. Perovskite surfaces were modeled by a multi-layer slab and at least $p(3 \times 3)$ supercells, where the two uppermost layers were fully relaxed and the rest fixed to the bulk distances. In the surface calculations, the Brillouin zone was sampled by a Γ -centered k points mesh from the Monkhorst-Pack method, and the k point samplings were denser than 30 \AA^{-1} . The vacuum between the slabs was at least 9 \AA . and the adsorbates were placed only on one side of the slab, and thus dipole correction was applied to remove spurious contributions arising from this asymmetry. In all cases, the optimization thresholds were 10^{-5} eV and 0.02 eV \AA^{-1} for electronic and ionic relaxations, respectively.

Table S5. The DFT surface energy relative parameters of the (010), (110) and (111) planes of CsPbBr_3 .

| CsPbBr_3 | (010) | (110) | (111) |
|---------------------------|------------|------------|------------|
| E_{slab} : slab energy | - 286.9825 | - 266.0951 | - 267.3768 |
| N:atoms | 135 | 135 | 135 |
| A: surface area | 309.3342 | 460.8569 | 564.4314 |
| γ : surface energy | 0.01960 | 0.05846 | 0.04546 |

^aper atom energy (E_{bulk}) in bulk is 2.1706 eV through the DFT calculations of the bulk CsPbBr_3 .

Table S6. The DFT slab energy (E_{slab}) and adsorption energy (E_a) about the slab models in the Fig. 3b and 3d.

| CsPbBr ₃ (010) | Slab energy | adsorption energy |
|---------------------------|-------------|-------------------|
| Bi-Bi/(010) ortho | -289.8214 | 2.1468 |
| Bi-Bi/(010) meta | -293.7857 | - 1.8175 |
| Bi/(010) | -288.0296 | 2.8029 |
| Bi-Pb/(010) | -293.0987 | - 1.2247 |

^aDFT-based Bisumth absorption energy is calculated by $E(\text{Bi/surface}) - E(\text{Bi atom}) - E(\text{surface})$, and that of Lead by $E(\text{Pb/surface}) - E(\text{Pb atom}) - E(\text{surface})$; at first, we calculated the slab energy of one Bi atom on CsPbBr₃(010), then the slab energy in Table S5 was used to evaluate adsorption energy after one Bi atom adsorbed on CsPbBr₃(010) surface.

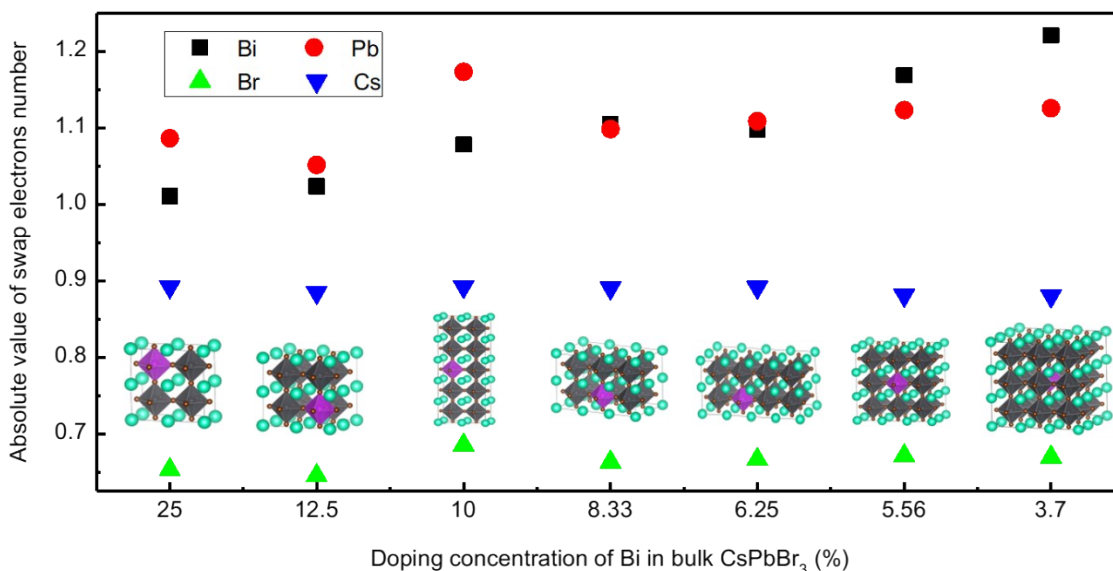
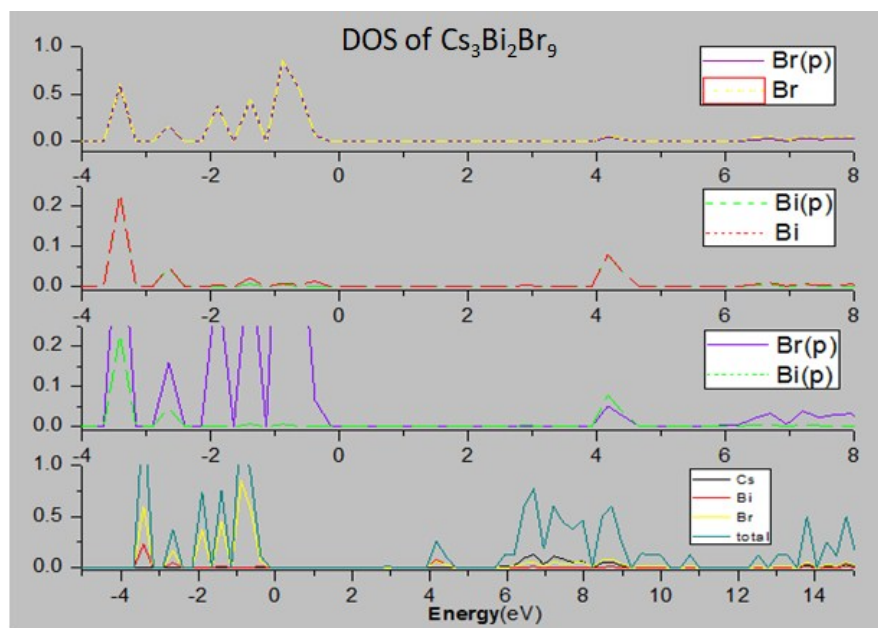
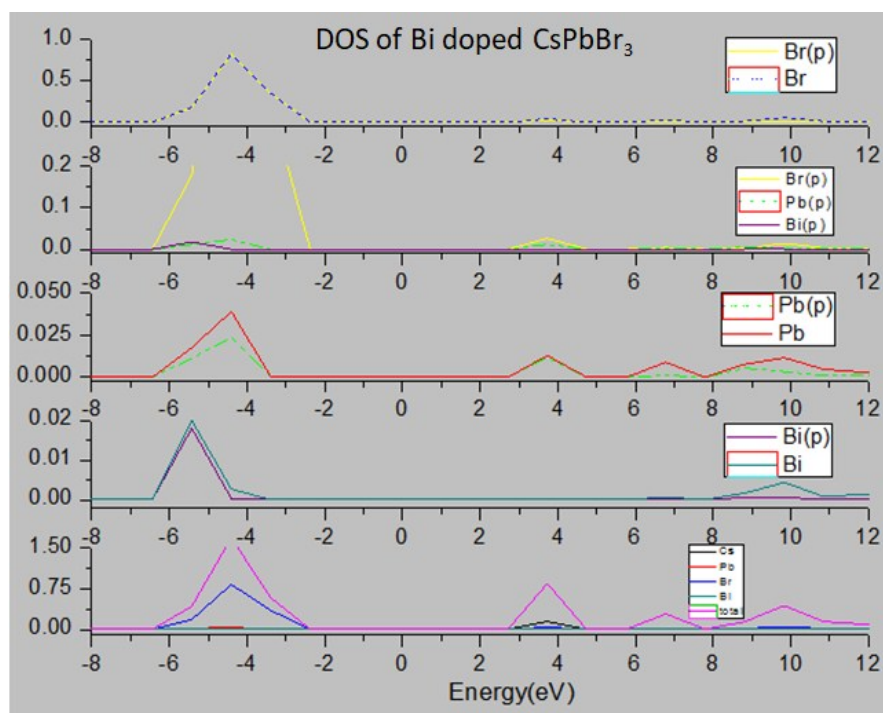


Fig. S27. Calculation of absolute values of swap electron number for Bi doped CsPbBr₃ in different super cells based on the Bader's analysis theory.



(a)



(b)

Fig. S28. The density of states of $\text{Cs}_3\text{Bi}_2\text{Br}_9$ and projected density of states of per atom (a), and the density of states of supposed Bi doped the bulk CsPbBr_3 (b).

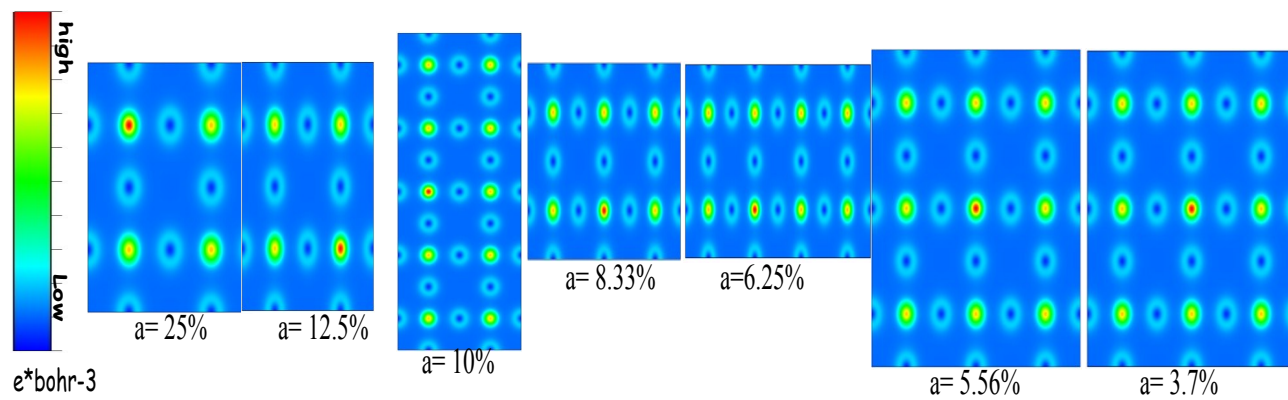


Fig. S29. The charge density of Bi doped the bulk CsPbBr_3 with different concentrates.